Innovative Service Around the Globe YAGEO

DATA SHEET

ANTI-SULFURATED CHIP RESISTORS AUTOMOTIVE GRADE

AF series

5%, 1%, 0.5%

sizes 0100/0201/0402/0603/0805/1206/1210/1218/2010/2512

RoHS compliant & Halogen free

Product specification – January 03, 2023 V.9

YAGEO

SCOPE

This specification describes AF0100 to AF2512 chip resistors with anti-sulfuration capabilities.

APPLICATIONS

- Industrial Equipment
- Power Application
- Networking Application
- High-end Computer & Multimedia Electronics in high sulfur environment
- Automotive electronics

FEATURES

- AEC-Q200 qualified
- Superior resistance against sulfur containing atmosphere
- Halogen free product and production
- RoHS compliant
- Reduces environmentally hazardous waste
- High component and equipment reliability
- Saving of PCB space
- Moisture sensitivity level: MSL 1
- 50ppm available

ORDERING INFORMATION - GLOBAL PART NUMBER

Part number is identified by the series name, size, tolerance, packaging type, temperature coefficient, taping reel and resistance value.

GLOBAL PART NUMBER

AF	XXXX	X	X	X	XX	XXXX	L
	(1)	(2)	(3)	(4)	(5)	(6)	(7)

(1) SIZE

0100/0201/0402/0603/0805/1206/1210/1218/2010/2512

(2) TOLERANCE

D = ±0.5%

F = ±1%

J = ±5% (for jumper ordering, use code of J)

(3) PACKAGING TYPE

R = Paper taping reel

K = Embossed plastic tape reel

(4) TEMPERATURE COEFFICIENT OF RESISTANCE

– = Base on spec

E = ±50 ppm/°C

(5) TAPING REEL

07 = 7 inch dia. Reel

13 = 13 inch dia. Reel

7W = 7 inch dia. Reel & 2 x standard power

(6) RESISTANCE VALUE

There are 2~4 digits indicated the resistance value. Letter R/K/M is decimal point.

Detailed resistance rules are displayed in the table of "Resistance rule of global part number".

(7) DEFAULT CODE

Letter L is system default code for ordering only (Note)

Resistance rule of global part number

Resistance coding rule	Example
XRXX (1 to 9.76 Ω)	1R = 1 Ω 1R5 = 1.5 Ω 9R76 = 9.76 Ω
XXRX (10 to 97.6 Ω)	10R = 10 Ω 97R6 = 97.6 Ω
XXXR (100 to 976 Ω)	100R = 100 Ω
XKXX (1 to 9.76 KΩ)	1K = 1,000 Ω 9K76 = 9760 Ω
XMXX (1 to 9.76 MΩ)	1M = 1,000,000 Ω 9M76= 9,760,000 Ω

ORDERING EXAMPLE

The ordering code for an AF0402 chip resistor, value 100 KΩ with ±1% tolerance, supplied in 7-inch tape reel with 10Kpcs quantity is: AF0402FR-07100KL.

NOTE

1. All our R-Chip products are RoHS compliant and Halogen free. "LFP" of the internal 2D reel label states "Lead-Free Process"
2. On customized label, "LFP" or specific symbol can be printed

MARKING

AF0100 / AF0201 / AF0402

Fig. 1

No marking

AF0603 / AF0805 / AF1206 / AF1210 / AF2010 / AF2512

Fig. 2 Value=10 KΩ

E-24 series: 3 digits, ±5%, ≥10Ω
First two digits for significant figure and 3rd digit for number of zeros

AF0603

Fig. 3 Value = 24 Ω

E-24 series: 3 digits, ±1%
One short bar under marking letter

Fig. 4 Value = 12.4 KΩ

E-96 series: 3 digits, ±1%
First two digits for E-96 marking rule and 3rd letter for number of zeros

AF0805 / AF1206 / AF1210 / AF2010 / AF2512

Fig. 5 Value = 10 KΩ

Both E-24 and E-96 series: 4 digits, ±1%
First three digits for significant figure and 4th digit for number of zeros

AF1218

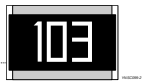

Fig. 6 Value = 10 KΩ

E-24 series: 3 digits, ±5%
First two digits for significant figure and 3rd digit for number of zeros

Fig. 7 Value = 10 KΩ

Both E-24 and E-96 series: 4 digits, ±1%
First three digits for significant figure and 4th digit for number of zeros

NOTE

For further marking information, please see special data sheet "Chip resistors marking". Marking of AF series is the same as RC series

CONSTRUCTION

The resistors are constructed on top of a high grade ceramic body. Internal metal electrodes are added at each end and connected by a resistive glaze. The resistive glaze is covered by a glass.
The composition of the glaze is adjusted to give the approximate required resistance value and laser trimming of this resistive glaze achieves the value within tolerance. The whole element is covered by a protective overcoat. Size 0603 and bigger is marked with the resistance value on top. Finally, the two external terminations (Ni / matte tin) are added. See fig.8

DIMENSIONS

Table 1 For outlines see fig. 8

TYPE	L (mm)	W (mm)	H (mm)	l_1 (mm)	l_2 (mm)
AF0100	0.40±0.02	0.20±0.02	0.14±0.02	0.10±0.03	0.10±0.03
AF0201	0.60±0.03	0.30±0.03	0.23±0.03	0.12±0.05	0.15±0.05
AF0402	1.00±0.05	0.50±0.05	0.35±0.05	0.20±0.10	0.25±0.10
AF0603	1.60±0.10	0.80±0.10	0.45±0.10	0.25±0.15	0.25±0.15
AF0805	2.00±0.10	1.25±0.10	0.50±0.10	0.35±0.20	0.35±0.20
AF1206	3.10±0.10	1.60±0.10	0.55±0.10	0.45±0.20	0.50±0.20
AF1210	3.10±0.10	2.60±0.15	0.57±0.10	0.45±0.20	0.50±0.20
AF1218	3.10±0.10	4.60±0.10	0.57±0.10	0.45±0.20	0.50±0.20
AF2010	5.00±0.10	2.50±0.15	0.57±0.10	0.55±0.20	0.55±0.20
AF2512	6.35±0.10	3.20±0.15	0.57±0.10	0.60±0.20	0.60±0.20

OUTLINES

For dimensions see Table 1

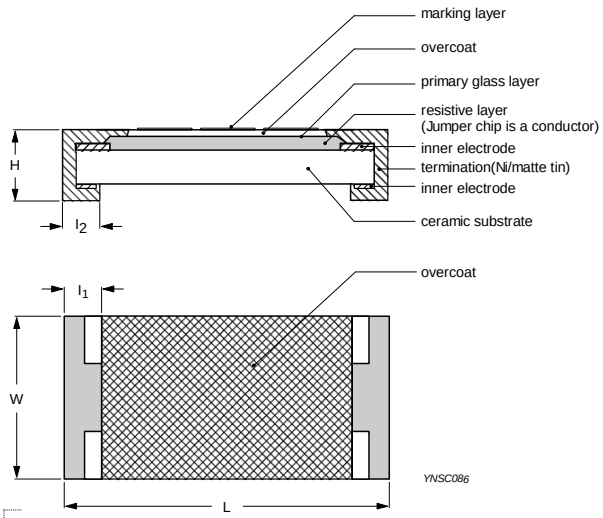

Fig. 8 Chip resistor outlines

ELECTRICAL CHARACTERISTICS

Table 2

TYPE	POWER	CHARACTERISTICS						
		Operating Temperature Range	Max. Working Voltage	Max. Overload Voltage	Dielectric Withstanding Voltage	Resistance Range	Temperature Coefficient	Jumper Criteria
AF0100	1/32 W	–55 °C to 125°C	15V	30V	30V	5% (E24) 10Ω ≤ R ≤ 1MΩ 1% (E24/E96) 10Ω ≤ R ≤ 1MΩ Jumper < 50mΩ	10Ω ≤ R < 100Ω ±300 ppm/°C 100Ω ≤ R ≤ 1MΩ ±200 ppm/°C	Rated Current 0.5A Max. Current 1.0A
AF0201	1/20 W		25V	50V	50V	5% (E24) 1Ω ≤ R ≤ 10MΩ 0.5%, 1% (E24/E96) 1Ω ≤ R ≤ 10MΩ Jumper < 50mΩ	1Ω ≤ R ≤ 10Ω -100/+350 ppm/°C 10Ω < R ≤ 10MΩ ±200 ppm/°C	Rated Current 0.5A Max. Current 1.0A
AF0402	1/16 W		50V	100V	100V	5% (E24) 1Ω ≤ R ≤ 22MΩ 0.5%, 1% (E24/E96) 1Ω ≤ R ≤ 10MΩ Jumper < 50mΩ	1Ω ≤ R ≤ 10Ω ±200 ppm/°C 10Ω < R ≤ 10MΩ ±100 ppm/°C 10MΩ < R ≤ 22MΩ ±200 ppm/°C 100Ω ≤ R ≤ 1MΩ ±50 ppm/°C	Rated Current 1A Max. Current 2A
	1/8W		75V	100V	100V	5% (E24) 1Ω ≤ R ≤ 10MΩ 0.5%, 1%, (E24/E96) 1Ω ≤ R ≤ 10MΩ	1Ω ≤ R < 10Ω ±200 ppm/°C 10Ω ≤ R ≤ 10MΩ ±100 ppm/°C	
AF0603	1/10 W		75V	150V	150V	5% (E24) 1Ω ≤ R ≤ 22MΩ 0.5%, 1% (E24/E96) 1Ω ≤ R ≤ 10MΩ Jumper < 50mΩ	1Ω ≤ R < 10Ω ±200 ppm/°C 10Ω ≤ R ≤ 10MΩ ±100 ppm/°C 10MΩ < R ≤ 22MΩ ±200 ppm/°C 100Ω ≤ R ≤ 10MΩ ±50 ppm/°C	Rated Current 1A Max. Current 2A
	1/5 W	–55 °C to 155 °C	75V	150V	150V	5% (E24) 1Ω ≤ R ≤ 10MΩ 0.5%, 1%, (E24/E96) 1Ω ≤ R ≤ 10MΩ	1Ω ≤ R < 10Ω ±200 ppm/°C 10Ω ≤ R ≤ 10MΩ ±100 ppm/°C	
AF0805	1/8 W		150V	300V	300V	5% (E24) 1Ω ≤ R ≤ 22MΩ 0.5%, 1% (E24/E96) 1Ω ≤ R ≤ 10MΩ Jumper < 50mΩ	1Ω ≤ R < 10Ω ±200 ppm/°C 10Ω ≤ R ≤ 10MΩ ±100 ppm/°C 10MΩ < R ≤ 22MΩ ±200 ppm/°C 100Ω ≤ R ≤ 10MΩ ±50 ppm/°C	Rated Current 2A Max. Current 5A
	1/4 W		150V	300V	300V	5% (E24) 1Ω ≤ R ≤ 10MΩ 0.5%, 1%, (E24/E96) 1Ω ≤ R ≤ 10MΩ	1Ω ≤ R < 10Ω ±200 ppm/°C 10Ω ≤ R ≤ 10MΩ ±100 ppm/°C	
AF1206	1/4 W		200V	400V	500V	5% (E24) 1Ω ≤ R ≤ 22MΩ 0.5%, 1% (E24/E96) 1Ω ≤ R ≤ 10MΩ Jumper < 50mΩ	1Ω ≤ R < 10Ω ±200 ppm/°C 10Ω ≤ R ≤ 10MΩ ±100 ppm/°C 10MΩ < R ≤ 22MΩ ±200 ppm/°C 100Ω ≤ R ≤ 10MΩ ±50 ppm/°C	Rated Current 2A Max. Current 10A
	1/2 W		200V	400V	500V	5% (E24) 1Ω ≤ R ≤ 10MΩ 0.5%, 1%, (E24/E96) 1Ω ≤ R ≤ 10MΩ	1Ω ≤ R < 10Ω ±200 ppm/°C 10Ω ≤ R ≤ 10MΩ ±100 ppm/°C	

ELECTRICAL CHARACTERISTICS

Table 2

TYPE	POWER	CHARACTERISTICS						
		Operating Temperature Range	Max. Working Voltage	Max. Overload Voltage	Dielectric Withstanding Voltage	Resistance Range	Temperature Coefficient	Jumper Criteria
AF1210	1/2 W	–55 °C to 155 °C	200V	500V	500V	5% (E24) 1Ω ≤ R ≤ 10MΩ 0.5%, 1% (E24/E96) 1Ω ≤ R ≤ 10MΩ Jumper < 50mΩ	1Ω ≤ R < 10Ω ±200 ppm/°C 10Ω ≤ R ≤ 10MΩ ±100 ppm/°C 100Ω ≤ R ≤ 1MΩ ±50 ppm/°C	Rated Current 2A Max. Current 10A
	1 W		200V	500V	500V	5% (E24) 1Ω ≤ R ≤ 10MΩ 0.5%, 1% (E24/E96) 1Ω ≤ R ≤ 10MΩ	1Ω ≤ R < 10Ω ± 200 ppm/°C 10Ω ≤ R ≤ 10MΩ ± 100 ppm/°C	
AF1218	1 W		200V	500V	500V	5% (E24) 1Ω ≤ R ≤ 1MΩ 0.5%, 1% (E24/E96) 1Ω ≤ R ≤ 1MΩ Jumper < 50mΩ	1Ω ≤ R < 10Ω ±200 ppm/°C 10Ω ≤ R ≤ 1MΩ ±100 ppm/°C 100Ω ≤ R ≤ 2.2MΩ ±50 ppm/°C	Rated Current 2A Max. Current 10A
	1.5 W		200V	500V	500V	5% (E24) 1Ω ≤ R ≤ 1MΩ 0.5%, 1% (E24/E96) 1Ω ≤ R ≤ 1MΩ	1Ω ≤ R < 10Ω ± 200 ppm/°C 10Ω ≤ R ≤ 1MΩ ± 100 ppm/°C	
AF2010	3/4 W		200V	500V	500V	5% (E24) 1Ω ≤ R ≤ 10MΩ 0.5%, 1% (E24/E96) 1Ω ≤ R ≤ 10MΩ Jumper < 50mΩ	1Ω ≤ R < 10Ω ±200 ppm/°C 10Ω ≤ R ≤ 10MΩ ±100 ppm/°C 100Ω ≤ R ≤ 10MΩ ±50 ppm/°C	Rated Current 2A Max. Current 10A
	1.25W		200V	500V	500V	5% (E24) 1Ω ≤ R ≤ 10MΩ 0.5%, 1% (E24/E96) 1Ω ≤ R ≤ 10MΩ	1Ω ≤ R < 10Ω ± 200 ppm/°C 10Ω ≤ R ≤ 10MΩ ± 100 ppm/°C	
AF2512	1 W		200V	500V	500V	5% (E24) 1Ω ≤ R ≤ 10MΩ 0.5%, 1% (E24/E96) 1Ω ≤ R ≤ 10MΩ Jumper < 50mΩ	1Ω ≤ R < 10Ω ±200 ppm/°C 10Ω ≤ R ≤ 10MΩ ±100 ppm/°C 100Ω ≤ R ≤ 10MΩ ±50 ppm/°C	Rated Current 2A Max. Current 10A
	2 W		200V	500V	500V	5% (E24) 1Ω ≤ R ≤ 10MΩ 0.5%, 1% (E24/E96) 1Ω ≤ R ≤ 10MΩ	1Ω ≤ R < 10Ω ± 200 ppm/°C 10Ω ≤ R ≤ 10MΩ ± 100 ppm/°C	

FOOTPRINT AND SOLDERING PROFILES

For recommended footprint and soldering profiles of AF-series is the same as RC-series. Please see the special data sheet "Chip resistors mounting".

PACKING STYLE AND PACKAGING QUANTITY

Table 3 Packing style and packaging quantity

PACKING STYLE	REEL DIMENSION	AF0100	AF0201	AF0402	AF0603 AF0805 AF1206	AF1210	AF1218 AF2010 AF2512
Paper taping reel (R)	7" (178 mm)	20,000	10,000/20,000	10,000/20,000	5,000	5,000	--
	13" (330 mm)	--	50,000	50,000	20,000	20,000	--
Embossed taping reel (K)	7" (178 mm)	--	--	--	--	--	4,000

NOTE

1. For paper/embossed tape and reel specification/dimensions, please see the special data sheet "Chip resistors packing".

FUNCTIONAL DESCRIPTION

OPERATING TEMPERATURE RANGE

AF0100 Range: -55°C to + 125°C

AF0201 - AF2512 Range: -55°C to + 155°C

POWER RATING

Each type rated power at 70°C:

AF0100=1/32W (0.03125W)

AF0201=1/20W (0.05W)

AF0402=1/16 W (0.0625W); 1/8W (0.125W)

AF0603=1/10 W (0.1W); 1/5W (0.2W)

AF0805=1/8 W (0.125W); 1/4W (0.25W)

AF1206=1/4 W (0.25W); 1/2W (0.5W)

AF1210=1/2W (0.5W); 1W

AF1218=1W; 1.5W

AF2010=3/4W (0.75W); 1.25W

AF2512=1W, 2W

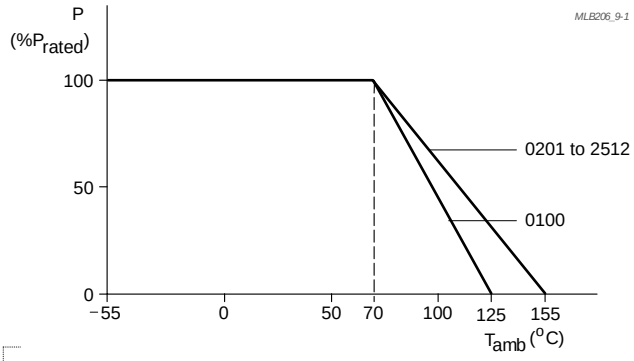

Fig. 9 Maximum dissipation (P_{max}) in percentage of rated power as a function of the operating ambient temperature (T_{amb})

RATED VOLTAGE

The DC or AC (rms) continuous working voltage corresponding to the rated power is determined by the following formula:

$$V = \sqrt{(P \times R)}$$

Where

V = Continuous rated DC or AC (rms) working voltage (V)

P = Rated power (W)

R = Resistance value (Ω)

TESTS AND REQUIREMENTS

Table 4 Test condition, procedure and requirements

TEST	TEST METHOD	PROCEDURE	REQUIREMENTS
Temperature Coefficient of Resistance (T.C.R.)	IEC 60115-1 4.8 MIL-STD-202 Method 304	At +25/–55°C and +25/+125°C **Formula:** $T.C.R=\frac{R_2-R_1}{R_1(t_2-t_1)}\times 10^6$ (ppm/°C) Where t_1=+25°C or specified room temperature t_2=–55°C or +125°C test temperature R_1=resistance at reference temperature in ohms R_2=resistance at test temperature in ohms	Refer to table 2
Life/Endurance	IEC 60115-1 4.25 MIL-STD-202 Method 108	At 70±2°C for 1,000 hours, RCWV applied for 1.5 hours on, 0.5 hour off, still-air required	0100: ±(3.0%+0.05 Ω) Others: ±(1.0%+0.05 Ω) <100 mΩ for Jumper
High Temperature Exposure	MIL-STD-202 Method 108	0100: 1,000 hours at 125°C Others: 1,000 hours at 155±3°C unpowered	0100: ±(2.0%+0.05 Ω) <50 mΩ for Jumper Others: ±(1.0%+0.05 Ω) <100 mΩ for Jumper
Moisture Resistance	MIL-STD-202 Method 106	Each temperature / humidity cycle is defined at 8 hours, 3 cycles / 24 hours for 10d. with 25°C / 65°C 95% R.H, without steps 7a & 7b, unpowered Parts mounted on test-boards, without condensation on parts	0100: ±(2.0%+0.05 Ω) <50 mΩ for Jumper Others: ±(0.5%+0.05 Ω) for 0.5%, 1% tol. ±(1.0%+0.05 Ω) for 5% tol. <100 mΩ for Jumper
Thermal Shock	MIL-STD-202 Method 107	–55 / +125°C Number of cycles required is 300. Devices mounted Maximum transfer time is 20 seconds. Dwell time is 15 minutes	0100: ±(1.0%+0.05 Ω) <50 mΩ for Jumper Others: ±(0.5%+0.05 Ω) for 0.5%, 1% tol. ±(1%+0.05 Ω) for 5% tol. <100 mΩ for Jumper
Short Time Overload	IEC60115-1 4.13	2.5 times of rated voltage or maximum overload voltage whichever is less for 5 seconds at room temperature	0100: ±(2.0%+0.05 Ω) Others: ±(1.0%+0.05 Ω) <50 mΩ for Jumper No visible damage
Bending	IEC 60115-1 4.33	Chips mounted on a 90 mm glass epoxy resin PCB (FR4) Bending : 0100/0201/0402: 5 mm 0603/0805: 3 mm 1206 & above: 2 mm Bending time: 60±5 seconds	±(1.0%+0.05 Ω) 0100: <50 mΩ for Jumper Others: <100 mΩ for Jumper No visible damage

TEST	TEST METHOD	PROCEDURE	REQUIREMENTS
Biased Humidity	MIL-STD-202 method 103	1,000 hours; 85°C /85%R.H., 10% of operating power. Measurement at 24±4 hours after test conclusion.	0100: ±(5%+0.05Ω) <50 mΩ for Jumper Others: 1Ω ≤ R ≤ 1MΩ: ±(3%+0.05Ω) 1MΩ < R ≤ 10MΩ: ±(5%+0.05Ω) <100 mΩ for Jumper
Solderability - Resistance to Soldering Heat	IEC 60115-1 4.18 MIL-STD-202 Method 215	Condition B, no pre-heat of samples Lead-free solder, 260±5°C, 10±1 seconds immersion time Procedure 2 for SMD: devices fluxed and cleaned with isopropanol	0100: ±(1.0%+0.05Ω) Others: ±(0.5%+0.05Ω) for 0.5%, 1% tol. ±(1.0%+0.05Ω) for 5% tol. <50 mΩ for Jumper No visible damage
- Wetting	J-STD-002	Electrical test not required Magnification 10X SMD conditions: Others: (a) Method B, aging 4 hours at 155°C dry heat, lead-free solder bath at 245°C (b) Method B, dipping at 215°C for 3 seconds 0100: 1st step: Method B, aging 4 hours at 155°C dry heat 2nd step: Lead free solder bath at 245°C	Well tinned (≥95% covered) No visible damage
FOS	ASTM-B-809-95* * Modified	Sulfur 750 hours, 105°C. unpowered	0100: ±(5.0%+0.05Ω) Others: ±(4.0%+0.05Ω) <100 mΩ for Jumper

REVISION HISTORY

REVISION	DATE	CHANGE NOTIFICATION	DESCRIPTION
Version 9	Jan. 03, 2023	-	- 10ohm TCR upgrade to 100ppm, for 0603~2512 normal power and 0402~2512 double power.
Version 8	Mar. 26, 2021	-	- Add TCR 50ppm and size 01005 extend
Version 7	Nov. 1, 2019	-	- Add in AF double power
Version 6	Sep. 05, 2019	-	- Updated dimensions
Version 5	Jun. 21, 2016	-	- Update test and requirement
Version 4	Dec. 24, 2015	-	- Update Dielectric Withstanding Voltage& Resistance value
Version 3	Apr. 01, 2015	-	- Modified test and requirements
Version 2	Nov. 20, 2014	-	- Tests and requirement update
Version 1	Sep. 27, 2013	-	- Size 0201/1210/1218/2010/2512 extend
Version 0	Jan 07, 2011	-	- First issue of this specification

单击下面可查看定价，库存，交付和生命周期等信息

>>Yageo(国巨)